## NSN 5962-01-232-9679

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-232-9679

## Body Length:

1.260 inches

#### Body Width:

Between 0.350 inches and 0.390 inches

#### **Body Height:**

Between 0.150 inches and 0.210 inches

#### **Maximum Power Dissipation Rating:**

400.0 milliwatts

#### **Operating Tempurature Range:**

-55.0 to 125.0 degrees celsius

#### Storage Tempurature Range:

-65.0 to 150.0 degrees celsius

#### **End Application:**

1055-01-192-0357

#### Features Provided:

Hermetically sealed and burn in and schottky and bipolar and 3-state output and low power

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

16 input

#### Criticality Code Justification:

Feat

#### **Current Rating Per Characteristic:**

-30.00 milliamperes input and 5.00 milliamperes input

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.00 volts power source

## Capitance Rating Per Characteristic:

4.00 input picofarads and 7.00 output picofarads

## Time Rating Per Chacteristic:

75.00 nanoseconds access

## Memory Device Type:

Ram

#### **Special Features:**

Nuclear hardness critical item

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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## AeroBase Group

## Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

Fiig:

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